



Product Summary

BV _{DSS}	Rds(on) Max	I _D Max T _A = +25°C
100V	$35m\Omega @ V_{GS} = 10V$	6.2A

Description and Applications

This MOSFET is designed to minimize the on-state resistance (RDs(ON)) yet maintain superior switching performance, making it ideal for high-efficiency power-management applications.

- Wireless charging
- DC-DC converters
- Power managements

Features and Benefits

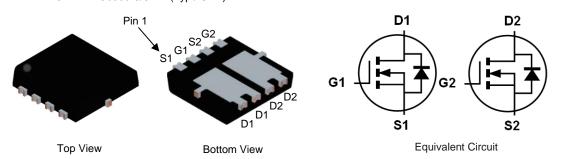
- Rated to +175°C Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching (UIS) Test in Production Ensures More Reliable and Robust End Application

POWERDI3333-8

- Low R_{DS(ON)} Ensures On-State Losses are Minimized
- Low Input Capacitance
- Fast Switching Speed
- Wettable Flank for Improved Optical Inspection
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability.
 - https://www.diodes.com/quality/product-definitions/
- An automotive-compliant part is available under separate datasheet (DMTH10H032SDVWQ)

Mechanical Data

- Package: POWERDI®3333-8
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208(3)
- Weight: 0.03 grams (Approximate)



Ordering Information (Note 4)

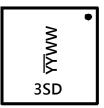
Part Number	Backago	Packing		
Fait Nulliber	Package	Qty.	Carrier	
DMTH10H032SDVW-7	POWERDI®3333-8/SWP (Type UXD)	2,000	Tape & Reel	
DMTH10H032SDVW-13	POWERDI®3333-8/SWP (Type UXD)	3,000	Tape & Reel	

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. 2. See http://www.diodes.com/quality/lead_free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and
<1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



 $\frac{3SD}{YY} = Product Type Marking Code$ $\frac{YY}{YY} = Date Code Marking$ $\frac{YY}{Y} = Last Two Digits of Year (ex: 24 = 2024)$ WW = Week Code (01 to 53)

POWERDI®3333-8/SWP (Type UXD)



Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage	Vdss	100	V		
Gate-Source Voltage	Vgss	±20	V		
	$T_A = +25^{\circ}C$	١D	6.2	A	
Continuous Drain Current, V _{GS} = 10V (Note 5) State			T _A = +100°C		4.4
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	Ідм	36	A		
Maximum Continuous Body Diode Forward Current (I	Is	2.6	A		
Pulsed Body Diode Forward Current (10µs Pulse, Du	d Body Diode Forward Current (10µs Pulse, Duty Cycle = 1%)		lsм	36	A
Avalanche Current, L = 0.3mH	I _{AS}	13	A		
Avalanche Energy, L = 0.3mH			Eas	25.3	mJ

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 6)	T _A = +25°C	PD	1.4	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	Reja	107	°C/W
Total Power Dissipation (Note 5)	T _A = +25°C	PD	2.7	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	R _{0JA}	55	°C/W
Thermal Resistance, Junction to Case (Note 5)	Rejc	5.5	°C/W	
Operating and Storage Temperature Range		TJ, TSTG	-55 to +175	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BVDSS	100	—		V	$V_{GS} = 0V, I_D = 1mA$	
Zero Gate Voltage Drain Current	IDSS		—	1	μA	$V_{DS} = 80V, V_{GS} = 0V$	
Gate-Source Leakage	lgss		—	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	VGS(TH)	2	—	4	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	
Static Drain-Source On-Resistance	RDS(ON)		27	35	mΩ	$V_{GS} = 10V, I_{D} = 5A$	
Diode Forward Voltage	V _{SD}	_	0.8	1.0	V	$V_{GS} = 0V, I_S = 5A$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	Ciss		544	—	рF		
Output Capacitance	Coss		181		рF	Vps = 50V, Vgs = 0V, f = 1MHz	
Reverse Transfer Capacitance	Crss		6.0	_	pF		
Gate Resistance	Rg	_	1.2	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge (V _{GS} = 4.5V)	Qg		4.3	—	nC		
Total Gate Charge (V _{GS} = 10V)	Qg	_	8.0	_	nC	V _{DS} = 50V, I _D = 7A	
Gate-Source Charge	Qgs		1.8		nC	VDS = 50V, ID = 7A	
Gate-Drain Charge	Qgd		2.4	_	nC		
Turn-On Delay Time	t _{D(ON)}		8.5		ns	$V_{DS} = 50V, I_D = 7A$ $V_{GS} = 10V, R_{GEN} = 6\Omega$	
Turn-On Rise Time	t _R		2.7	_	ns		
Turn-Off Delay Time	tD(OFF)	_	11.9	_	ns		
Turn-Off Fall Time	tF		6.2		ns		
Reverse Recovery Time	trr		33.2		ns		
Reverse Recovery Charge	Q _{RR}		34.3		nC	I _F = 7A, di/dt = 100A/µs	

Notes: 5. Device mounted on FR-4 substrate PCB, 2oz copper, with thermal bias to bottom layer 1 inch square copper plate.

Device mounted on FR-4 PCB, with minimum recommended pad layout.
Short duration pulse test used to minimize self-heating effect.

8. Guaranteed by design. Not subject to product testing.



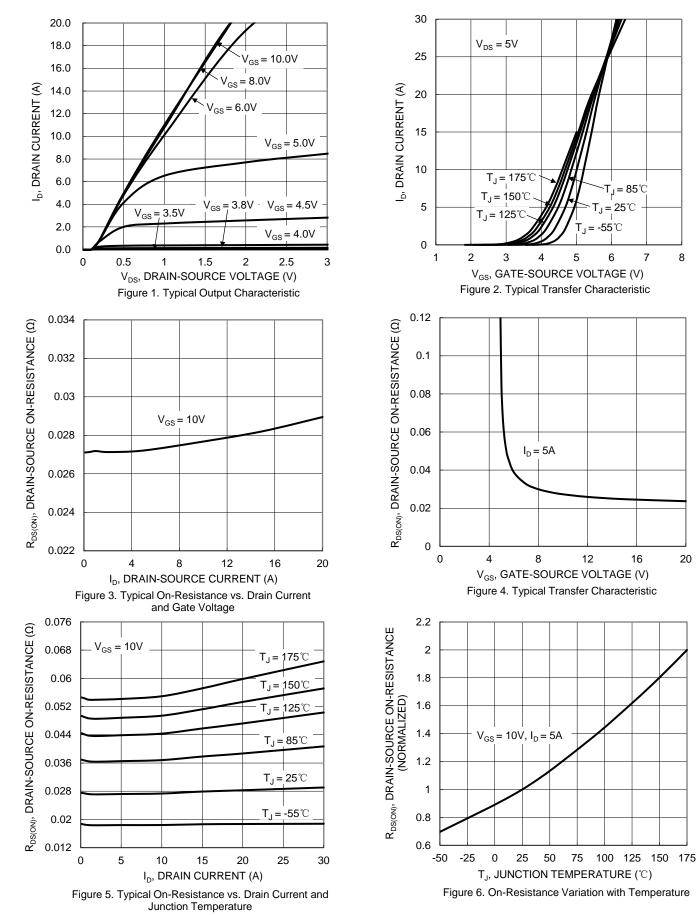
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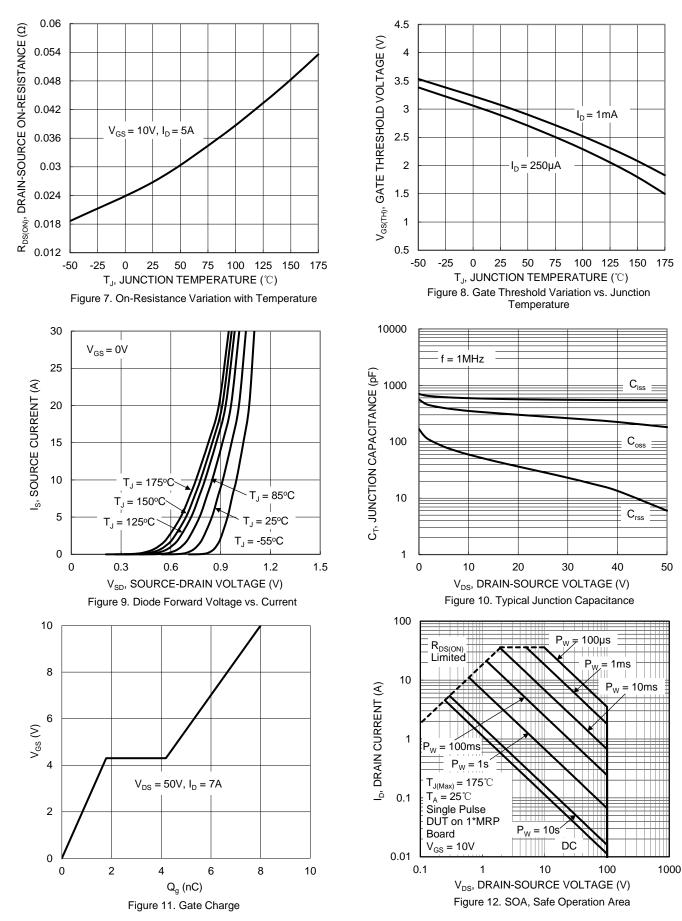
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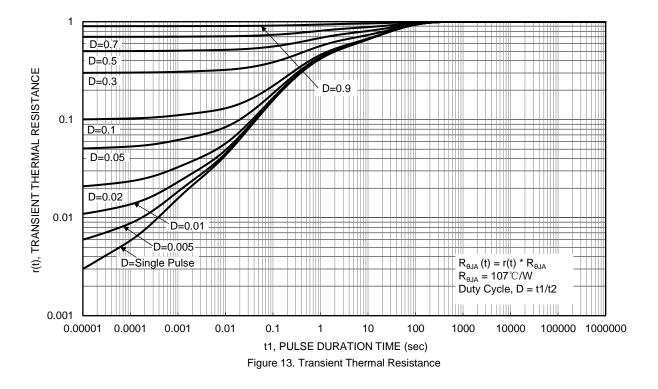


DMTH10H032SDVW



DMTH10H032SDVW Document number: DS45573 Rev. 2 - 2

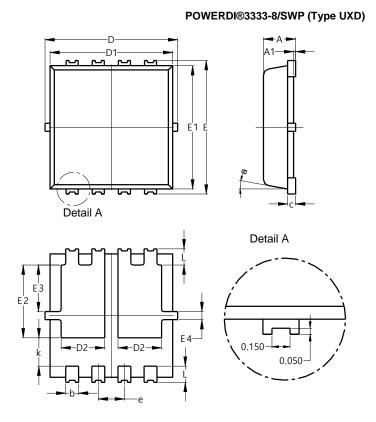






Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

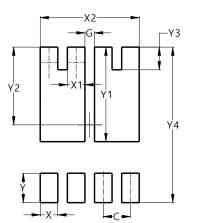


POWERDI [®] 3333-8/SWP						
(Type UXD)						
Dim	Min	Max	Тур			
Α	0.75	0.85	0.80			
A1	0.00	0.05	-			
b	0.25	0.40	0.32			
C	0.10	0.25	0.15			
D	3.20	3.40	3.30			
D1	2.95	3.15	3.05			
D2	1.00	1.20	1.10			
Е	3.20	3.40	3.30			
E1	2.95	3.15	3.05			
E2	1.60	2.00	1.80			
E3	0.95	1.35	1.15			
E4	0.10	0.30	0.20			
е	_	_	0.65			
L	0.30	0.50	0.40			
k	0.50	0.90	0.70			
а	0°	12°	10°			
All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

POWERDI®3333-8/SWP (Type UXD)



Dimensions	Value (in mm)
С	0.650
G	0.230
Х	0.420
X1	0.420
X2	2.370
Y	0.700
Y1	2.250
Y2	1.850
Y3	0.540
Y4	3.700



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